NSN 5961-00-837-7064

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-837-7064 **Inclosure Material:** Metal **Overall Length:** 0.885 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-64 **Mounting Method:** Threaded stud **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 repetitive peak off-state voltage and 1.8 on-state voltage, dc **Current Rating Per Characteristic:** 4.70 amperes forward current, total rms nanoamperes and 80.00 milliamperes forward current, total rms peak **Maximum Operating Tempurature Per Measurement Point:** 159.0 degrees celsius case **Special Features:** Junction pattern arrangement: pnpn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0